

20 V, P-channel Trench MOSFET

21 March 2014

**Product data sheet** 

## 1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Fast switching
- Trench MOSFET technology
- 2 kV ESD protection
- AEC-Q101 qualified

# 3. Applications

- Relay driver
- High-speed line driver
- High-side loadswitch
- Switching circuits

### 4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-20	V
V <sub>GS</sub>	gate-source voltage	-		-12	-	12	V
I <sub>D</sub>	drain current	$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s	[1]	-	-	-5.7	А
Static characteristics							
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -3 A; T <sub>j</sub> = 25 °C		-	41	46	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

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# 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		D
2	D	drain		
3	G	gate		G ( T
4	S	source	TSOP6 (SOT457)	
5	D	drain		
6	D	drain		S 017aaa259

# 6. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
PMN42XPEA	TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457		

# 7. Marking

Table 4. Marking codes	
Type number	Marking code
PMN42XPEA	В9

# 8. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-20	V
V <sub>GS</sub>	gate-source voltage			-12	12	V
I <sub>D</sub>	drain current	$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s	[1]	-	-5.7	А
		$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C	[1]	-	-4	А
		$V_{GS}$ = -4.5 V; $T_{amb}$ = 100 °C	[1]	-	-2.9	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-16	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	500	mW
			[1]	-	1310	mW
		T <sub>sp</sub> = 25 °C		-	8330	mW

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Symbol	Parameter	Conditions		Min	Max	Unit
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drai	n diode	·	· · · ·			
l <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	-1.4	А
ESD maximum rating						
V <sub>ESD</sub>	electrostatic discharge voltage	НВМ	[3]	-	2000	V

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] Measured between all pins.

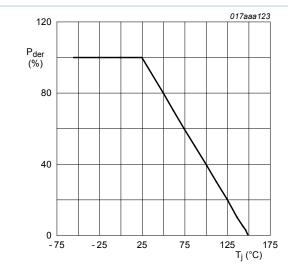


Fig. 1. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

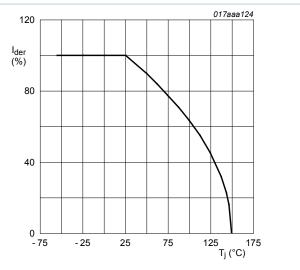


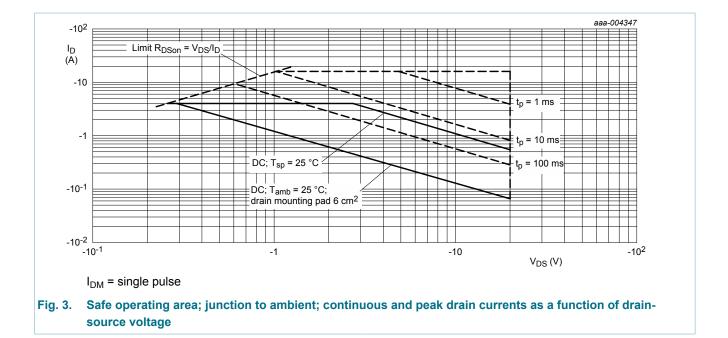
Fig. 2. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100 \%$$

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# 9. Thermal characteristics

Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
ui(j-a)	thermal resistance	in free air	[1]	-	216	250	K/W
	from junction to		[2]	-	83	95	K/W
	ampient	in free air; t ≤ 5 s	[2]	-	51	60	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	10	15	K/W

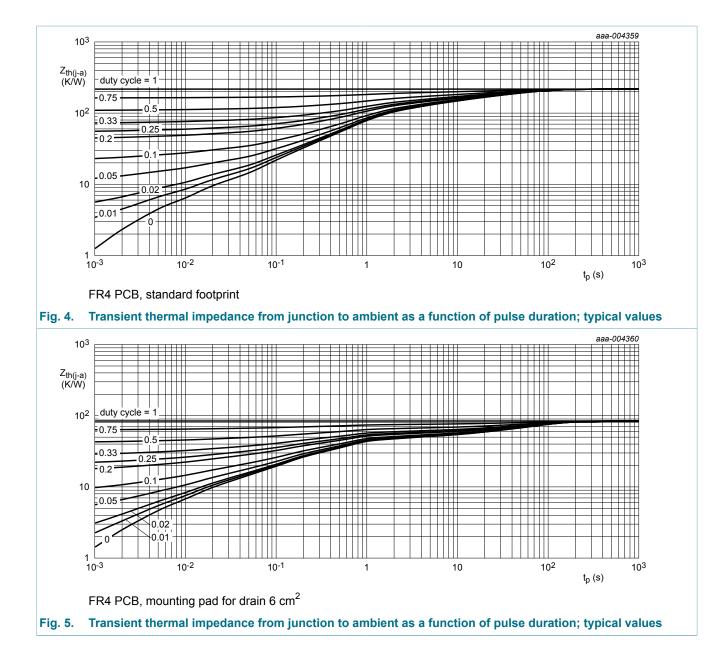
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

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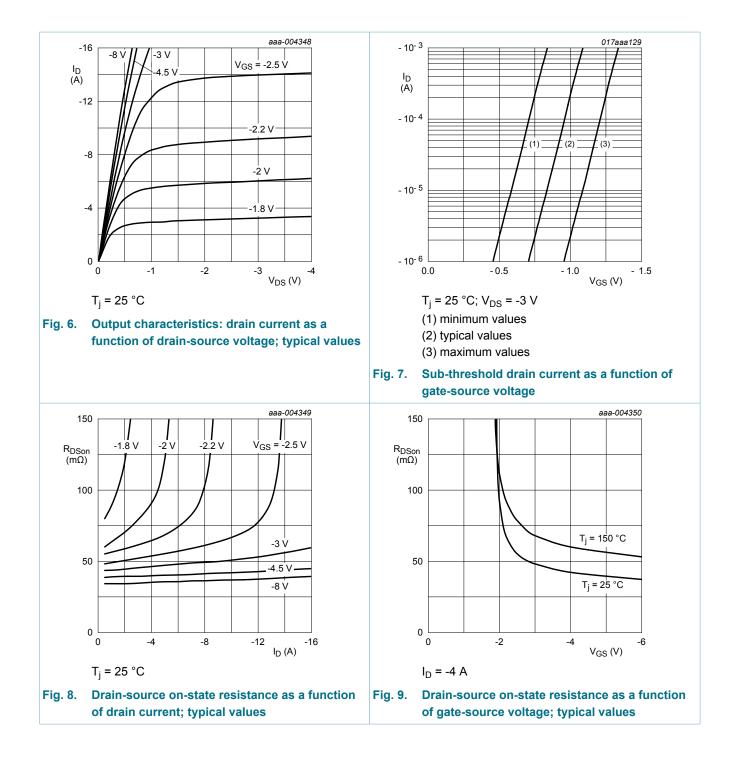
# **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static chara	acteristics		I			
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	I <sub>D</sub> = -250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-20	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	I <sub>D</sub> = -250 μA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = 25 °C	-0.75	-1	-1.25	V
I <sub>DSS</sub> drain leaka	drain leakage current	$V_{DS}$ = -20 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	-	-1	μA
		$V_{DS}$ = -20 V; $V_{GS}$ = 0 V; $T_{amb}$ = 150 °C	-	-	-10	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 12 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		$V_{GS}$ = -12 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-10	μA
R <sub>DSon</sub> drain-source on-state resistance	drain-source on-state	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -3 A; T <sub>j</sub> = 25 °C	-	41	46	mΩ
	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -3 A; T <sub>j</sub> = 150 °C	-	56	64	mΩ	
		V <sub>GS</sub> = -2.5 V; I <sub>D</sub> = -3 A; T <sub>j</sub> = 25 °C	-	56	64	mΩ
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = -10 V; I <sub>D</sub> = -4 A; T <sub>j</sub> = 25 °C	-	12.5	-	S
Dynamic ch	naracteristics	· · ·	I			
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = -10 V; I <sub>D</sub> = -4 A; V <sub>GS</sub> = -4.5 V;	-	11.5	17.3	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	2.7	-	nC
Q <sub>GD</sub>	gate-drain charge		-	2.4	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = -10 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	1410	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	207	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	148	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = -10 V; I <sub>D</sub> = -4 A; V <sub>GS</sub> = -4.5 V;	-	17	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	27	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	33	-	ns
t <sub>f</sub>	fall time		-	27	-	ns
Source-dra	in diode	· · · ·	1	_		
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -1.2 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	-0.7	-1.2	V

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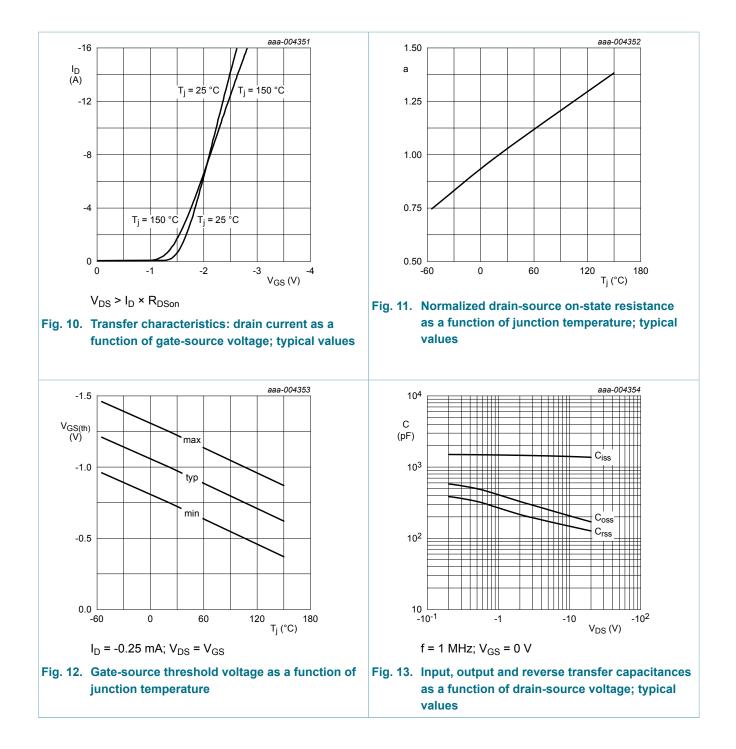
# **PMN42XPEA**

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# **PMN42XPEA**

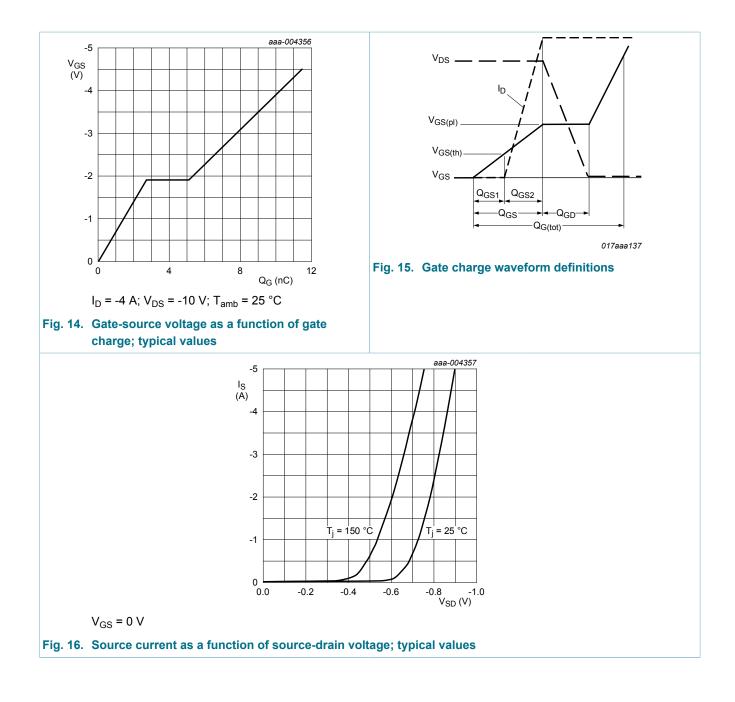
### 20 V, P-channel Trench MOSFET



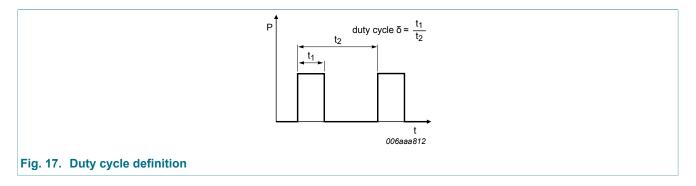
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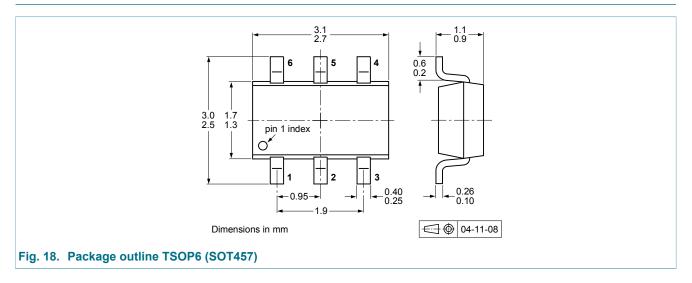
### 11. Test information



### **11.1 Quality information**

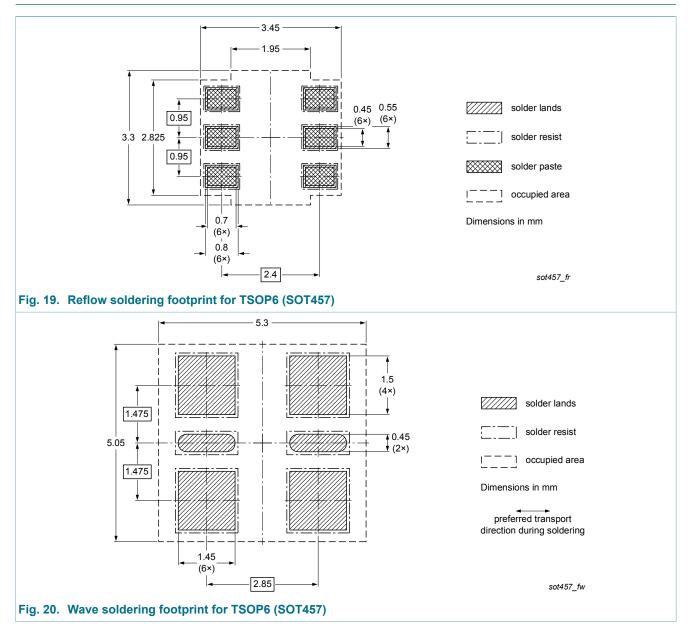
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

### 12. Package outline



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# **13. Soldering**



# 14. Revision history

Table 8. Revision his	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMN42XPEA v.1	20140321	Product data sheet	-	-

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#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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